NSN 5961-01-005-5532

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-005-5532 **Inclosure Material:** Plastic **Overall Length:** 0.340 inches **Terminal Length:** Between 0.400 inches and 0.500 inches **Overall Diameter:** 0.230 inches **Mounting Method: Terminal Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 3.0 reverse voltage, dc **Current Rating Per Characteristic:** 2.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 140.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0